

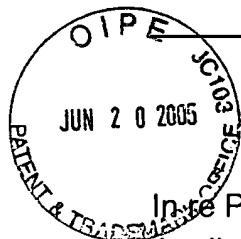
10/684,890 *C of C*

CERTIFICATE OF MAILING

I hereby certify that this paper (along with any paper or item referred to as being attached or enclosed) is being deposited with the United States Postal Service on the date shown below with sufficient postage as first-class mail in an envelope addressed to Commissioner for Patents, PO Box 1450, Alexandria, VA 22313-1450.

Date: 6/17/05

Christine Arndt
Christine Arndt



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE Certificate

JUN 24 2005

of Correction

In re Patent No.: 6,903,407 B1

Applicant: Kang

Issue Date: Jun. 7, 2005

For: NON VOLATILE CHARGE TRAPPING DIELECTRIC MEMORY
CELL STRUCTURE WITH GATE HOLE INJECTION ERASE

Docket No. H0742

**REQUEST FOR CERTIFICATE OF CORRECTION OF PATENT
FOR APPLICANT MISTAKE (37 CFR 1.323) AND PTO MISTAKE (37 CFR 1.322(a))**

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

06/21/2005 MWOLDGE1 00000027 180988 6903407
01 FC:1811 100.00 DA

Attention: Decision and Certificate of Correction
Branch of the Patent Issue Division

Sir:

Request is made for issuance of a certificate of correction to correct applicant and PTO mistakes in the printing of the subject patent. Attached hereto in duplicate is form PTO/SB/44 with at least one copy being suitable for printing.

For the correction at column 1, line 27, the correct language can be found in the application at page 1, lines 20-21.

For the correction at column 1, line 54, the correct language can be found in the application at page 2, line 8.

For the correction at column 2, line 14, the correct language can be found in the application at page 2, line 29.

For the correction at column 2, line 50, the correct language can be found in the application at page 3, line 24.

JUN 27 2005

For the correction at column 3, line 16, the correct language can be found in the application at page 4, line 19.

For the correction at column 4, line 8, the correct language can be found in the application at page 6, line 11.

For the correction at column 4, line 23, the correct language can be found in the application at page 6, line 21.

For the correction at column 6, lines 42-43, the correct language can be found in the application at page 10, line 19.

For the correction at column 8, line 27, the correct language can be found in the application at page 13, line 22.

For the correction at column 8, line 57, the correct language can be found in the application at page 14, line 14.

For the correction at column 8, line 60, the correct language can be found in the application at page 14, line 16.

The correction at column 3, line 12, is necessary to fix the typographical error which resulted in the symbol for silicon being shown as "Xi" rather than the correct "Si". This error was made in good faith by the Applicant's representative.

The correction at column 5, line 2, is necessary to fix the typographical error which resulted in the symbol for silicon being shown as "Xi" rather than the correct "Si". This error was made in good faith by the Applicant's representative.

The correction at claim 8, line 3, is necessary to fix the typographical error which resulted in the symbol for silicon being shown as "Xi" rather than the correct "Si". This error was made in good faith by the Applicant's representative.

The correction at claim 15, line 3, is necessary to fix the typographical error which resulted in the symbol for silicon being shown as "Xi" rather than the correct "Si". This error was made in good faith by the Applicant's representative.

The correction at claim 22, line 3, is necessary to fix the typographical error which resulted in the symbol for silicon being shown as "Xi" rather than the correct "Si". This error was made in good faith by the Applicant's representative.

As all errors were either due to PTO mistake or were clerical in nature, the corrections should not constitute new matter and should not require re-examination.

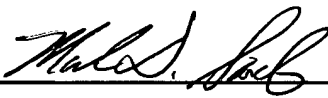
Issuance of a certificate of correction for the subject patent is respectfully requested. The Commissioner is hereby authorized to charge \$100.00 in satisfaction of the fee under 37 CFR 1.20(a) to Deposit Account No. 18-0988, our Docket No. AMDSPH0742US.. However, if any additional fees are required please charge same to our Deposit Account No. 18-0988.

Please send the Certificate to:

RENNER, OTTO, BOISSELLE & SKLAR, LLP
1621 Euclid Avenue - Nineteenth Floor
Cleveland, OH 44115

Respectfully submitted,

RENNER, OTTO, BOISSELLE & SKLAR, LLP



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UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO. : 6,903,407 B1

DATED : Jun. 7, 2005

INVENTOR(S) : Kang

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 1, line 27, replace "negative. charge" with --negative charge--

Column 1, line 54, replace "swept Into the" with --swept into the--

Column 2, line 14, replace "its Interface with" with --its interface with--

Column 2, line 50, replace "gate Is positively" with --gate is positively--

Column 3, line 12, replace "ZrXi_x O_y" with --ZrSi_xO_y--

Column 3, line 16, replace "present Invention" with --present invention--

Column 4, line 8, replace "n-type Implanted" with --n-type implanted--

Column 4, line 23, replace "electrons In a" with --electrons in a--

Column 5, line 2, replace "ZrXi_xO_y" with --ZrSi_xO_y--

Column 6, lines 42-43, replace "more specifically,. the" with --more specifically, the--

Column 8, lines 27, replace "forming Insulating nitride" with --forming insulating nitride--

Column 8, lines 57, replace "this Invention has" with --this invention has--

Column 8, lines 60, replace "skilled In the art" with --skilled in the art--

Claim 8, line 3, replace "ZrXi_xO_y" with --ZrSi_xO_y--

Claim 15, line 3, replace "ZrXi_xO_y" with --ZrSi_xO_y--

Claim 22, line 3, replace "ZrXi_xO_y" with --ZrSi_xO_y--

MAILING ADDRESS OF SENDER:

Renner, Otto, Boisselle & Sklar, LLP
1621 Euclid Avenue, Nineteenth Floor
Cleveland, OH 44115

PATENT NO. 6,903,407 B1

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This collection of information is required by 37 CFR 1.322, 1.323, and 1.324. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 1.0 hour to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Attention Certificate of Corrections Branch, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

If you need assistance in completing the form, call 1-800-PTO-9199 and select option 2.

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